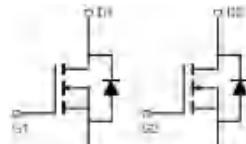
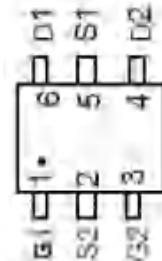


## Feature

- 30V,4A
- $R_{DS(on)} < 40m\Omega$  @  $V_{GS}=4.5V$  TYP:31 m  $\Omega$
- $R_{DS(on)} < 60m\Omega$  @  $V_{GS}=2.5V$  TYP:46 m  $\Omega$
- Advanced Trench Technology
- Lead free product is acquired



Schematic diagram



Marking and pin Assignment



SOT23-6L top view

## Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity (PCS)
6802	AP6802	Sot-23-6	7 inch	-	3000

## ABSOLUTE MAXIMUM RATINGS ( $T_a=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	30	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current ( $T_a = 25^\circ C$ )	$I_D$	4	A
Continuous Drain Current ( $T_a = 70^\circ C$ )	$I_D$	2.6	A
Pulsed Drain Current	$I_{DM}$	16	A
Power Dissipation	$P_D$	0.96	W
Thermal Resistance from Junction to Ambient <sup>(4)</sup>	$R_{\theta JA}$	130	°C/W
Junction Temperature	$T_J$	150	°C
Storage Temperature	$T_{STG}$	-55~+150	°C

**MOSFET ELECTRICAL CHARACTERISTICS( $T_a=25^\circ C$  unless otherwise noted)**

Parameter	Symbol	Test Condition	Min	Type	Max	Unit
<b>Static Characteristics</b>						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	30	-	-	V
Zero gate voltage drain current	$I_{DSS}$	$V_{DS} = 30V, V_{GS} = 0V$	-	-	1	$\mu A$
Gate-body leakage current	$I_{GSS}$	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	$\pm 100$	nA
Gate threshold voltage <sup>(3)</sup>	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	1.0	1.5	2.5	V
Drain-source on-resistance <sup>(3)</sup>	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 4A$	-	31	40	$m\Omega$
		$V_{GS} = 4.5V, I_D = 3A$	-	46	60	
<b>Dynamic characteristics</b>						
Input Capacitance	$C_{iss}$	$V_{DS} = 15V, V_{GS} = 0V, f = 1MHz$	-	233	-	$pF$
Output Capacitance	$C_{oss}$		-	44	-	
Reverse Transfer Capacitance	$C_{rss}$		-	33	-	
<b>Switching characteristics</b>						
Turn-on delay time	$t_{d(on)}$	$V_{DD} = 15V, I_D = 4A,$ $V_{GS} = 10V, R_G = 10\Omega$	-	4	-	$ns$
Turn-on rise time	$t_r$		-	2.1	-	
Turn-off delay time	$t_{d(off)}$		-	15	-	
Turn-off fall time	$t_f$		-	3.2	-	
Total Gate Charge	$Q_g$	$V_{DS} = 15V, I_D = 2A,$ $V_{GS} = 10V$	-	3	-	$nC$
Gate-Source Charge	$Q_{gs}$		-	0.5	-	
Gate-Drain Charge	$Q_{gd}$		-	0.8	-	
<b>Source-Drain Diode characteristics</b>						
Diode Forward voltage <sup>(3)</sup>	$V_{DS}$	$V_{GS} = 0V, I_S = 4A$	-	-	1.2	V
Diode Forward current <sup>(4)</sup>	$I_S$		-	-	4.0	A

**Notes:**

1. Repetitive Rating: pulse width limited by maximum junction temperature
2. Pulse Test: pulse width  $\leq 300\mu s$ , duty cycle  $\leq 2\%$
3. Surface Mounted on FR4 Board,  $t \leq 10$  sec

## Test Circuit

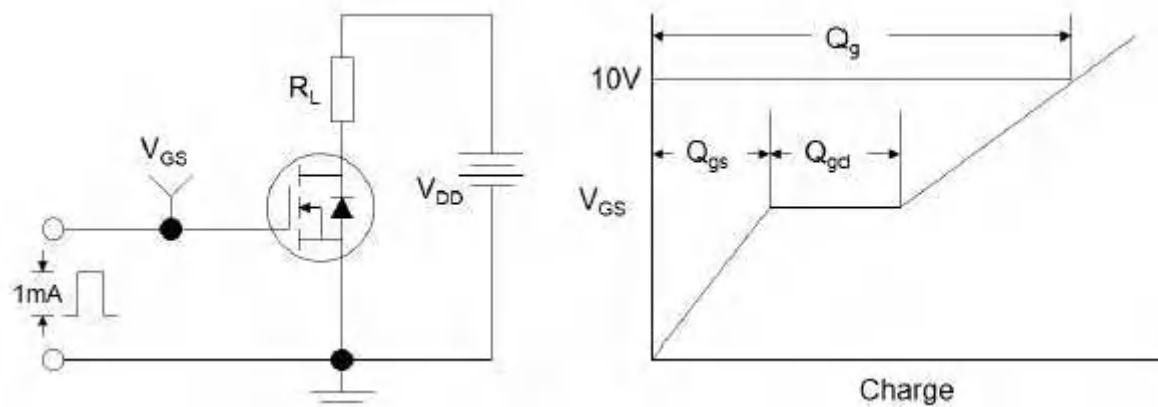


Figure1:Gate Charge Test Circuit & Waveform

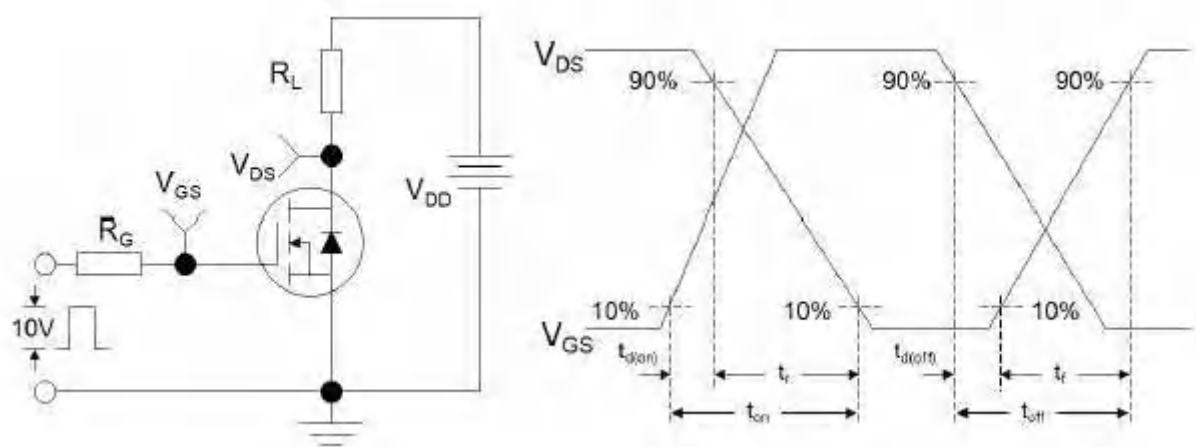


Figure 2: Resistive Switching Test Circuit & Waveforms

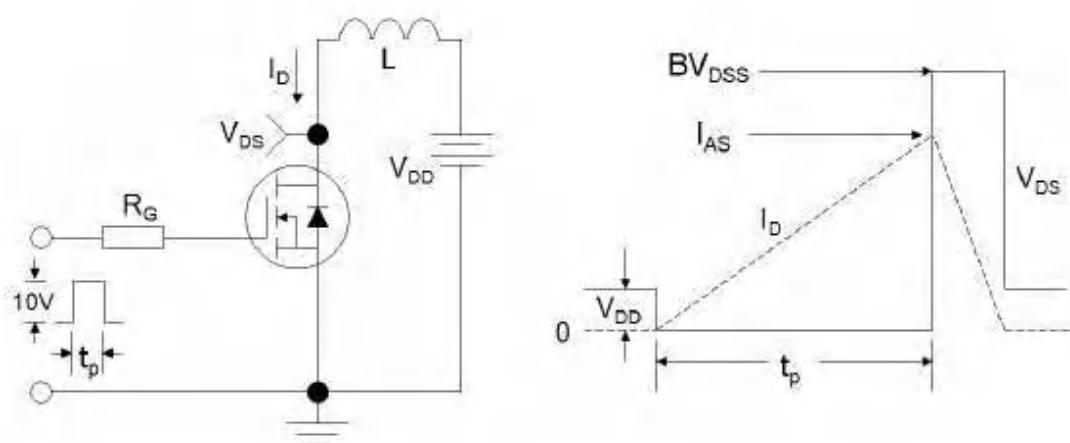
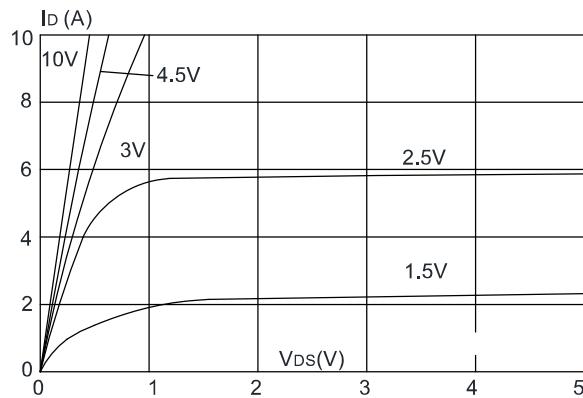


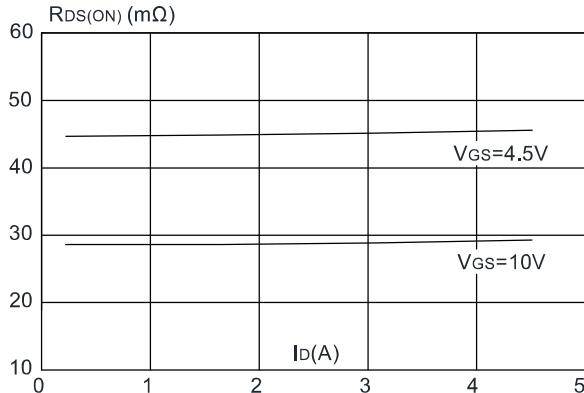
Figure 3:Unclamped Inductive Switching Test Circuit & Waveforms

## Typical Performance Characteristics

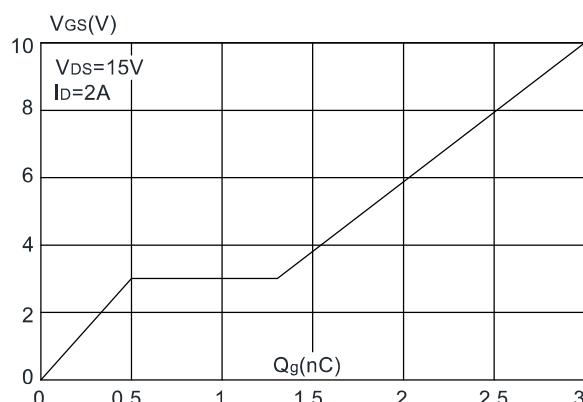
**Figure 1:** Output Characteristics



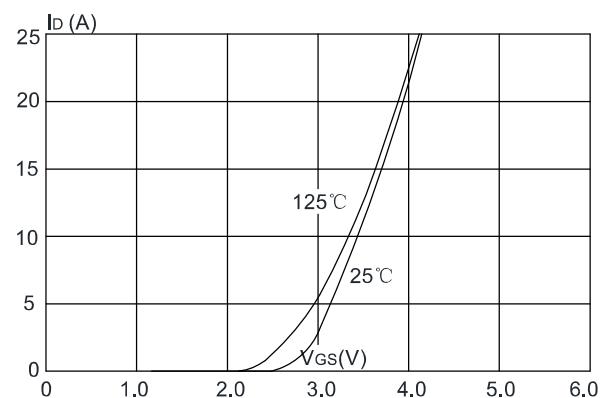
**Figure 3:** On-resistance vs. Drain Current



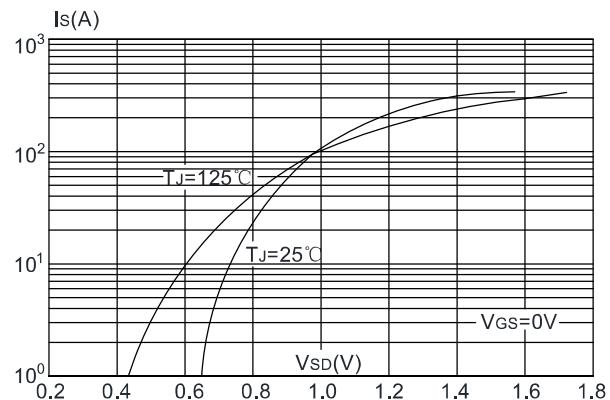
**Figure 5:** Gate Charge Characteristics



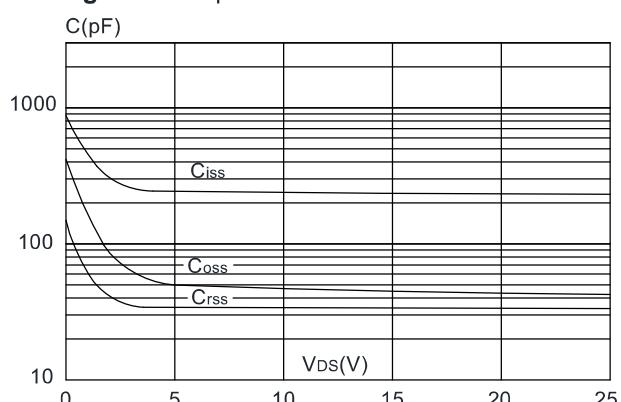
**Figure 2:** Typical Transfer Characteristics



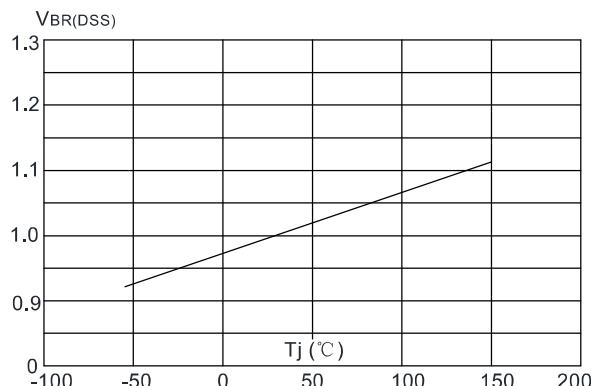
**Figure 4:** Body Diode Characteristics



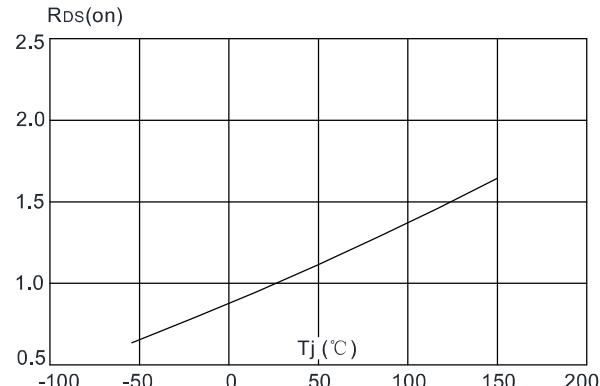
**Figure 6:** Capacitance Characteristics



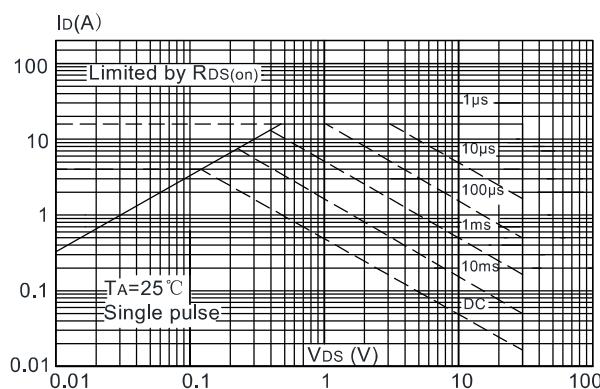
**Figure 7:** Normalized Breakdown Voltage vs. Junction Temperature



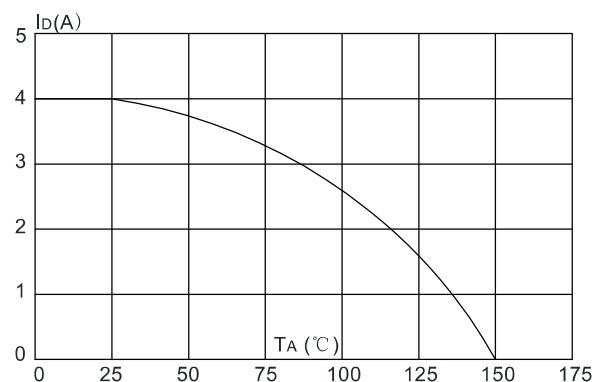
**Figure 8:** Normalized on Resistance vs. Junction Temperature



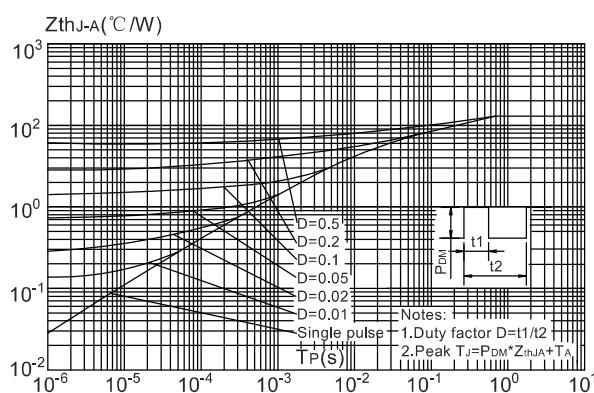
**Figure 9:** Maximum Safe Operating Area



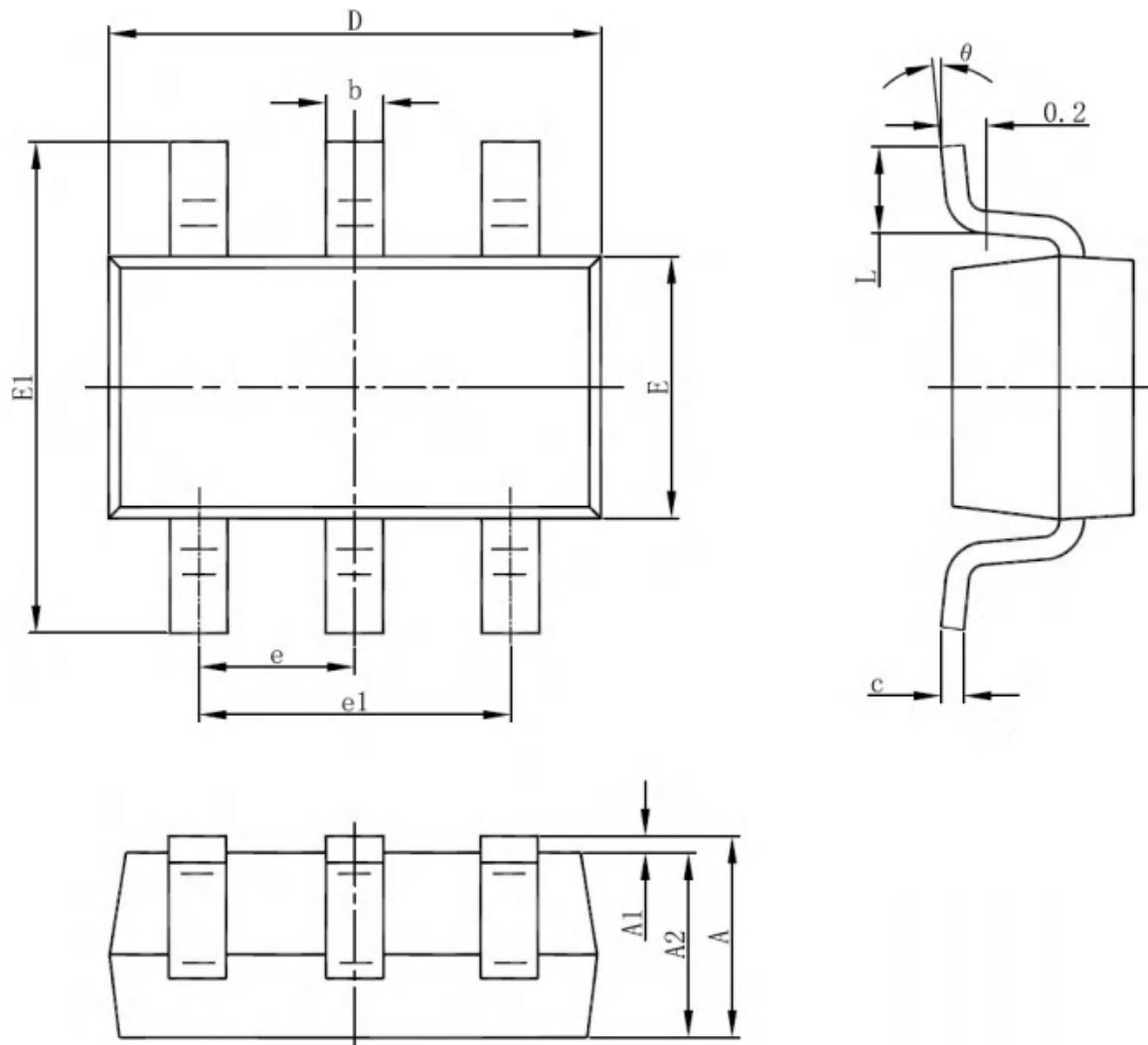
**Figure 10:** Maximum Continuous Drain Current vs. Ambient Temperature



**Figure 11:** Maximum Effective Transient Thermal Impedance, Junction-to-Ambient



## SOT23-6L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°